

SEMICONDUCTOR TECHNICAL DATA

KHB4D0N80P1/F1/F2

N CHANNEL MOS FIELD EFFECT TRANSISTOR

General Description

This planar stripe MOSFET has better characteristics, such as fast switching time, low on resistance, low gate charge and excellent avalanche characteristics. It is mainly suitable for electronic ballast and switch mode power supplies.

FEATURES

2008. 12. 15 Revision No : 1